NUP2105-Q
DIODE
AECQ-101, ESD PROTECTION DIODE

DESCRIPTION

The NUP2105-Q is available in SOT-23 package.

APPLICATIONS

- CAN bus protection
- Automotive applications

ORDERING INFORMATION

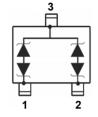
Package Type	Part Number		
SOT-23	NUP2105-Q		
SPQ	3,000pcs/Reel		
AiT provides all RoHS Compliant Products			

FEATURE

- Ultra-low leakage: nA level.
- Low clamping voltage
- Complies with IEC 61000-4-2 standards:
 - -Air discharge: ±30kV
 - -Contact discharge: ±30Kv
- AEC-Q101 Qualified.

PIN DESCRIPTION





ABSOLUTE MAXIMUM RATINGS TA = 25°C, unless otherwise specified.

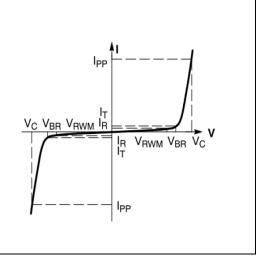
IEC 61000-4-2 (ESD)	Contact	±30kV
	Air	±30kV
PPP, Peak Pulse Power@8/20 µs		350W
IPP, Peak Pulse Current @8/20 μs		8A
T _J , Operating Temperature Range		-55°C ~ +150°C
T _{STG} , Storage Temperature Range		-55°C ~ +150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 T_A =25°C unless otherwise specified.

Symbols	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ IPP
V_{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ VRWM
V_{BR}	Breakdown Voltage @ IT
I _T	Test Current
I _F	Forward Current
V _F	Forward Voltage @ IF
Ppk	Peak Power Dissipation
С	Capacitance @ VR = 0 and f = 1MHz



Parameter		Symbol	Min	Тур	Max	Unit
VRWM, Reverse Stand-Off Voltage		V_{RWM}	-	-	24	V
Reverse Leakage Current	V _{RWM} = 24 V, Pin 1、2 to Pin 3		-	-	200	nA
	V _{RWM} = 24 V, Pin 3 to Pin 1、2	I _{RM}	-	-	200	
Breakdown Voltage	I _T = 5 mA, Pin 1、2 to Pin 3	.,	26.2	-	32	V
	I _T = 5 mA, Pin 3 to Pin 12	V _{BR}				
	I _{PP} = 3A (8 x 20μs pulse)		-	32	34	
Clamping Voltage	I _{PP} = 5A (8 x 20μs pulse)	Vc	-	34	36	V
	I _{PP} = 8A (8 x 20µs pulse)		-	37	39	
Junction Capacitance	VR = 0V, f = 1MHz	Сл	-	-	30	pF

TYPICAL CHARACTERISTICS

Fig 1. IPP vs. VC

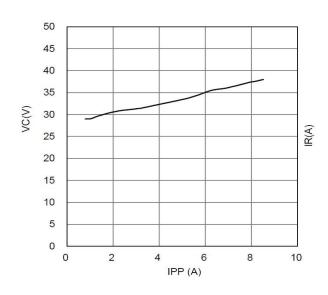


Fig 2. IR vs. VR

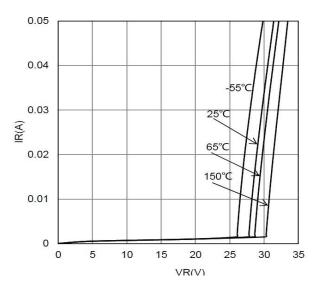


Fig 3. CT vs. VR

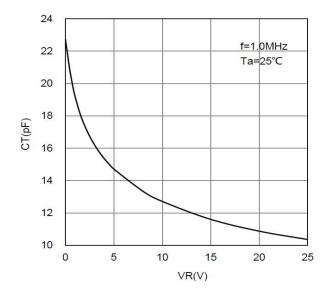
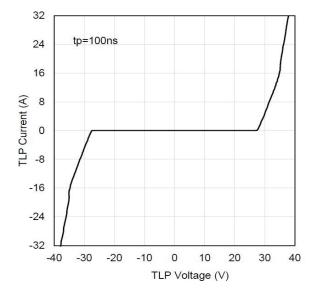


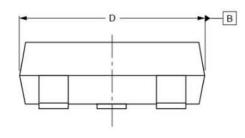
Fig 4. TLP Measure sent

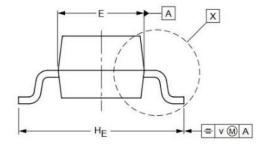


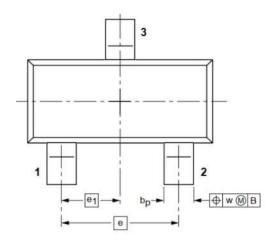


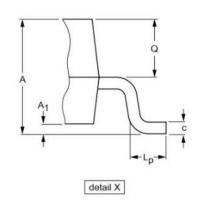
PACKAGE INFORMATION

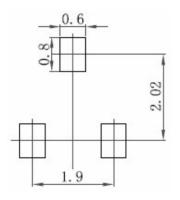
Dimension in SOT-23 (Unit: mm)











The recommended mounting pad size

SYMBOL	MIN	MAX		
А	0.900	1.150		
A1	0.100			
bp	0.380	0.480		
С	0.090	0.150		
D	2.800	3.000		
Е	1.200	1.400		
Е	1.900			
E1	0.950			
HE	2.100	2.550		
Lp	0.150	0.450		
Q	0.450	0.550		
V	0.200			
W	0.100			

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